

## GaAs MMIC Digital Attenuator Chip, DC-50GHz

#### Performance characteristics

Frequency range: DC-50GHz Insertion loss: 4.5dB typ Attenuation range: 1~31dB Bit Count: 5 digits Attenuation accuracy (RMS): 0.75dB Power supply voltage: -5V Control voltage: 0/+5V 50Ohm input/output Chip size: 2.2 x 1.2 x 0.1mm

#### **Product Introduction**

GDA-0050-5D-PD is a GaAs MMIC 5-bit Digital attenuator chip, with a frequency range of DC~50GHz, insertion loss of 4.5dB, switching speed of 50ns, integrated driver inside the chip, and 0/+5V control. The chip through-hole metallization process ensures good grounding, and the back is metallized, suitable for eutectic sintering or conductive adhesive bonding processes.

Usage restriction parameter <sup>1</sup>			
Power supply voltage range	-6V		
Control voltage range	-0.5V~+5.5V		
Maximum input power	+27dBm		
working temperature	-55 ~ +85°C		
Storage temperature	-65 ~ +150°C		

[1] Exceeding any of the above maximum limits may result in permanent damage.

Index	Minimum value	Typical value	Maximum value	Unit	
Frequency range		GHz			
Insertion loss	-	4.5	4.5 -		
Attenuation range	1~31			dB	
Attenuation step	1			dB	
Attenuation number	5			bite	
Attenuation accuracy (all frequency bands)	-	-	-1.5 ~ +2.6	dB	
Attenuation accuracy RMS	-	0.75	-	dB	
Additional phase shift	-	-	-9 ~ +29	degree	
Input return loss	-	22	-	dB	
Output Return Loss	-	21	-	dB	

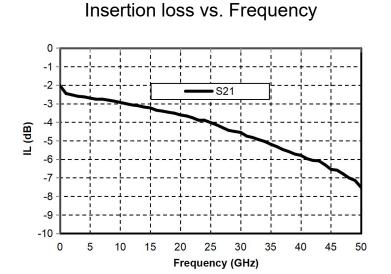


GDA-0050-5D-PD

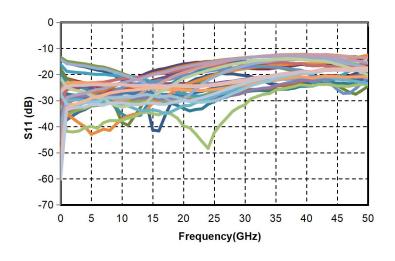
Switching speed	-	50	-	ns
P-1dB	-	22	-	dBm
Current	-	10	-	mA

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Main indicator testing curve

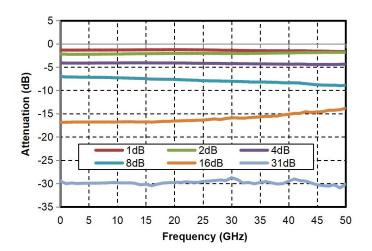


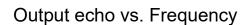
Input echo vs. Frequency

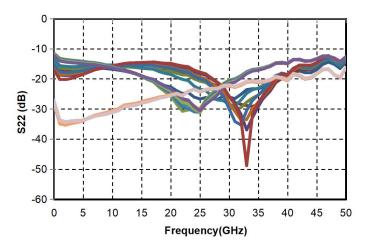


Attenuation accuracy vs. Frequency

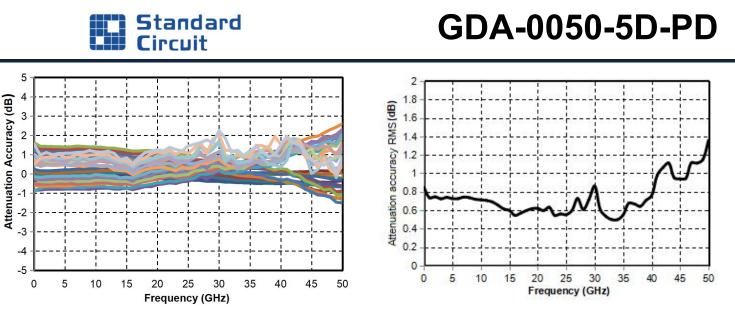
Reference attenuation state vs. Frequency



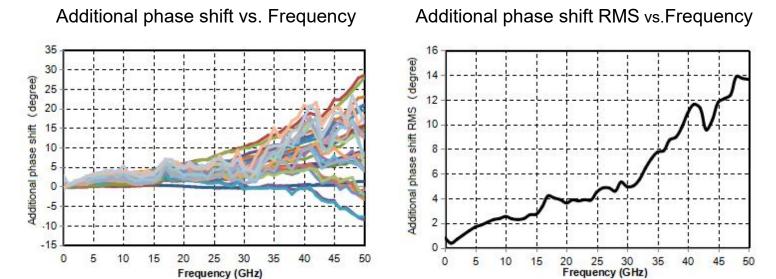


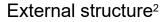


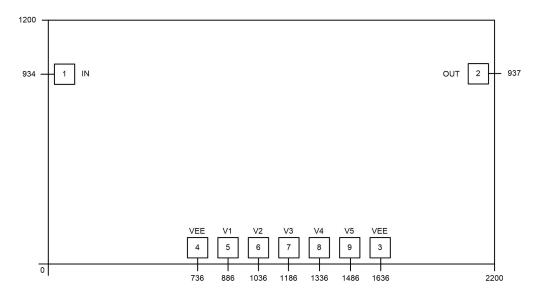
Attenuation accuracy RMS vs. Frequency











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[2] The units in the figure are all micrometers. (Boundary dimension tolerance:  $\pm$ 100um.)

Definition of bonding pressure point			
Bond point number	Functional	Function Description	
	symbols		
1	RF1	The signal input terminal is externally connected to a 50 ohm circuit, and there is no integrated DC isolation capacitor inside the chip	
2	RF2	The signal output terminal is externally connected to a 50 ohm circuit, and there is no integrated DC isolation capacitor inside the chip	
3、4	VEE	Chip power port	
5~9	VC	Attenuation control pads, refer to the truth table for attenuation control	
Chip bottom	GND	The bottom of the chip needs to have sufficient and good contact with RF and DC ground	

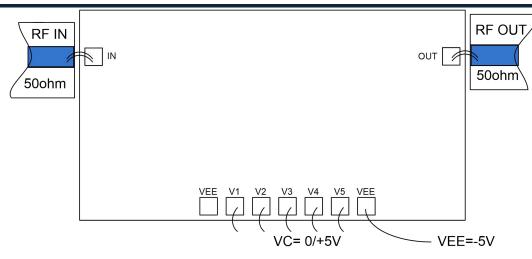
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V1	V2	V3	V4	V5	VEE	Conduction pathway	
0	0	0	0	0	-5V	Initial state N=0: attenuation amount is 0	
+5V	0 0 0 0	-5V	Attenuation state N=1: Attenuation				
+37			U	0	-5V	amount is 1	
0	+5V	0	0	0 -5V	E\/	Attenuation state N=2: Attenuation	
U					amount is 2		
0	0	+5V	0	0 -5\	5\/	Attenuation state N=4: Attenuation	
U	0		U		-5V	amount is 4	
0	0	0	+5V	0 -5V	5\/	Attenuation state N=8: Attenuation	
U	U				U	-3 v	amount is 8
0		0 0 +5V	0 0 0 +5V	0	+5\/	-5V	Attenuation state N=16: Attenuation
U	0		+57	-50	amount is 16		

Suggested assembly diagram



# GDA-0050-5D-PD



Connect the VEE on one side and control the solder pads without the need for external resistors.

### Precautions for use

- The chip needs to be stored in a container with anti-static function and stored in a nitrogen environment.
- Attempting to clean the surface of bare chips using wet chemical methods is prohibited.
- Please strictly comply with ESD protection requirements to avoid static damage to bare chips.
- Routine operation: Please use precision pointed tweezers to remove the bare chip. During the operation, avoid tools or fingers touching the surface of the chip.
- Suggestion for mounting operation: Bare chip installation can use AuSn solder eutectic sintering or conductive adhesive bonding process. The installation surface must be clean and flat.
- Sintering process: It is recommended to use AuSn solder sheets with a gold tin ratio of 80/20. The working surface temperature reached 255 °C, and the tool (vacuum chuck) temperature reached 265 °C. When a high-temperature mixed gas (nitrogen to hydrogen ratio of 90/10) is blown onto the chip, the temperature at the top of the tool should be raised to 290 °C. Do not let the chip stay above 320 °C for more than 20 seconds. The friction time should not exceed 3 seconds.
- Bonding process: The amount of conductive adhesive applied should be as small as possible. After placing the chip in the installation position, the conductive adhesive can be vaguely visible around it. Please follow the information provided by the conductive adhesive manufacturer for curing conditions.